MGSF1N02LT1

Preferred Device

Power MOSFET 750 mAmps, 20 Volts N-Channel SOT-23

These miniature surface mount MOSFETs low R_{DS(on)} assure minimal power loss and conserve energy, making these devices ideal for use in space sensitive power management circuitry. Typical applications are dc–dc converters and power management in portable and battery–powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low RDS(on) Provides Higher Efficiency and Extends Battery Life
- Miniature SOT-23 Surface Mount Package Saves Board Space

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	VDSS	20	Vdc
Gate-to-Source Voltage - Continuous	VGS	± 20	Vdc
Drain Current – Continuous @ $T_A = 25^{\circ}C$ – Pulsed Drain Current ($t_p \le 10 \ \mu s$)	ID IDM	750 2000	mA
Total Power Dissipation @ T _A = 25°C	PD	400	mW
Operating and Storage Temperature Range	TJ, Tstg	- 55 to 150	°C
Thermal Resistance – Junction-to-Ambient	R _{0JA}	300	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	10TL	260	°C

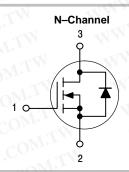
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胜特力	电子(深圳)	86-755-83298787	
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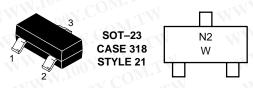
ON Semiconductor

http://onsemi.com

750 mAMPS 20 VOLTS RDS(on) = 90 mΩ



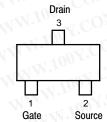




= Work Week

W





ORDERING INFORMATION

Device	Package	Shipping
MGSF1N02LT1	SOT-23	3000 Tape & Reel
MGSF1N02LT3	SOT–23	10,000 Tape & Reel

Preferred devices are recommended choices for future use and best overall value.

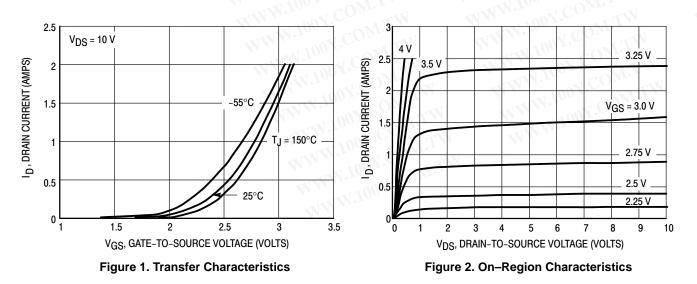
WW.100 MGSF1N02LT1

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WWW.100Y.COM.TW ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic			Min	Тур	Max	Unit
OFF CHARACTERISTICS	LINNN.100 X COM	L. L.	Viz	W.10-	N.COM	W
Drain–to–Source Breakdown Voltage (V _{GS} = 0 Vdc, I _D = 10 μAdc)			20	WWF.IO	oy.col	Vdc
Zero Gate Voltage Drain Current ($V_{DS} = 20$ Vdc, $V_{GS} = 0$ Vdc) ($V_{DS} = 20$ Vdc, $V_{GS} = 0$ Vdc, $T_J =$	= 125°C)	IDSS	- 1	NN-W.	1.0 10	μAdc
Gate-Body Leakage Current (VGS =	± 20 Vdc, V _{DS} = 0 Vdc)	IGSS	-	MENN	±100	nAdc
ON CHARACTERISTICS (Note 1.)	L.L.	COM		WW	N.Lon	COM
Gate Threshold Voltage ($V_{DS} = V_{GS}$, $I_D = 250 \mu$ Adc)	MTTA MMM.100	VGS(th)	1.0	1.7	2.4	Vdc
Static Drain-to-Source On-Resistan ($V_{GS} = 10 \text{ Vdc}, I_D = 1.2 \text{ Adc}$) ($V_{GS} = 4.5 \text{ Vdc}, I_D = 1.0 \text{ Adc}$)	^r DS(on)	UN UN	0.075 0.115	0.090 0.130	Ohms	
OYNAMIC CHARACTERISTICS	COM WWW	any.co.	WTN		MM	1001.
Input Capacitance	(V _{DS} = 5.0 Vdc)	C _{iss}	Vn-	125	MAIN.	pF
Output Capacitance	(V _{DS} = 5.0 Vdc)	C _{OSS}	Mr.	120	WW	1.100
Transfer Capacitance (V _{DG} = 5.0 Vdc)		C _{rss}	014.1	45	-	W.100
WITCHING CHARACTERISTICS (No	ote 2.)	W.1001.	Mon		V	VW.10
Turn–On Delay Time	me vite out of the second s		Ma	2.5	-74	ns
Rise Time	(V _{DD} = 15 Vdc, I _D = 1.0 Adc,	tr of		1.0	- 1	
Turn–Off Delay Time	R _L = 50 Ω)	td(off)	N.CO.	16		N.M.M.
Fall Time		tf	00 <u>-</u> 70	8.0	-	WWW
Gate Charge (See Figure 6)		QT		6000	- D	рС
SOURCE-DRAIN DIODE CHARACTE	RISTICS	.Www.	00 1	-0 _{W'r}		
Continuous Current	IS	100 X.	COM.	0.6	А	
Pulsed Current		ISM	I LOOY	Ma	0.75	
Forward Voltage (Note 2.)	V _{SD}		0.8	47	V 🔨	

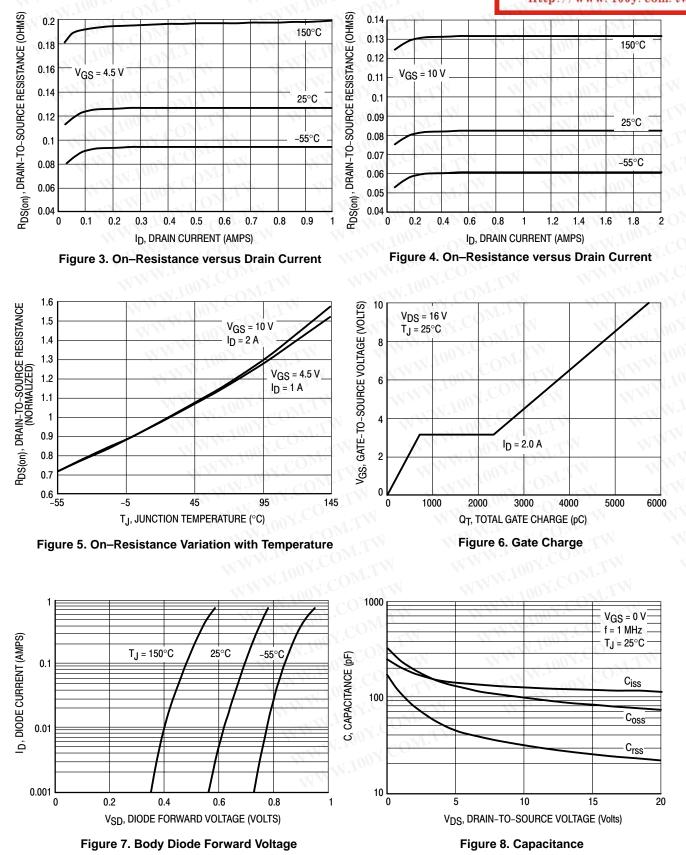
TYPICAL ELECTRICAL CHARACTERISTICS



MGSF1N02LT1

TYPICAL ELECTRICAL CHARACTERISTICS

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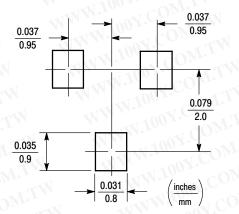


INFORMATION FOR USING THE SOT-23 SURFACE MOUNT PACKAGE

MINIMUM RECOMMENDED FOOTPRINT FOR SURFACE MOUNTED APPLICATIONS

Surface mount board layout is a critical portion of the total design. The footprint for the semiconductor packages must be the correct size to insure proper solder connection

interface between the board and the package. With the correct pad geometry, the packages will self align when subjected to a solder reflow process.



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SOT-23 POWER DISSIPATION

The power dissipation of the SOT–23 is a function of the drain pad size. This can vary from the minimum pad size for soldering to a pad size given for maximum power dissipation. Power dissipation for a surface mount device is determined by $T_{J(max)}$, the maximum rated junction temperature of the die, $R_{\theta JA}$, the thermal resistance from the device junction to ambient, and the operating temperature, T_A. Using the values provided on the data sheet for the SOT–23 package, P_D can be calculated as follows:

$$P_{D} = \frac{T_{J(max)} - T_{A}}{R_{\theta JA}}$$

The values for the equation are found in the maximum ratings table on the data sheet. Substituting these values into the equation for an ambient temperature T_A of 25°C,

one can calculate the power dissipation of the device which in this case is 416 milliwatts.

$$P_{D} = \frac{150^{\circ}C - 25^{\circ}C}{300^{\circ}C/W} = 416 \text{ milliwatts}$$

The 300°C/W for the SOT-23 package assumes the use of the recommended footprint on a glass epoxy printed circuit board to achieve a power dissipation of 416 milliwatts. There are other alternatives to achieving higher power dissipation from the SOT-23 package. Another alternative would be to use a ceramic substrate or an aluminum core board such as Thermal CladTM. Using a board material such as Thermal Clad, an aluminum core board, the power dissipation can be doubled using the same footprint.

SOLDERING PRECAUTIONS

The melting temperature of solder is higher than the rated temperature of the device. When the entire device is heated to a high temperature, failure to complete soldering within a short time could result in device failure. Therefore, the following items should always be observed in order to minimize the thermal stress to which the devices are subjected.

- Always preheat the device.
- The delta temperature between the preheat and soldering should be 100°C or less.*
- When preheating and soldering, the temperature of the leads and the case must not exceed the maximum temperature ratings as shown on the data sheet. When using infrared heating with the reflow soldering method, the difference shall be a maximum of 10°C.

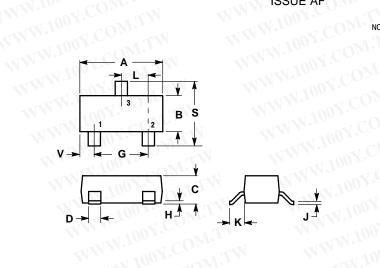
- The soldering temperature and time shall not exceed 260°C for more than 10 seconds.
- When shifting from preheating to soldering, the maximum temperature gradient shall be 5°C or less.
- After soldering has been completed, the device should be allowed to cool naturally for at least three minutes. Gradual cooling should be used as the use of forced cooling will increase the temperature gradient and result in latent failure due to mechanical stress.
- Mechanical stress or shock should not be applied during cooling.

* Soldering a device without preheating can cause excessive thermal shock and stress which can result in damage to the device.

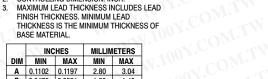
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PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AF**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH. JOY.COM.TW 2



	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.1102	0.1197	2.80	3.04
В	0.0472	0.0551	1.20	1.40
С	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
Ľ	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60

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